HL6503MG

Visible High Power Laser Diode for DVD-RAM

HITACHI

ADE-208-670D (Z) 5th Edition Dec. 2000

Description

The HL6503MG is a $0.66 \,\mu m$ band AlGalnP laser diode (LD) with a multi-quantum well (MQW) structure. It is suitable as a light source for large capacity optical disc memories, such as DVD-RAM, and various other types of optical equipment.

Hermetic sealing of the small package (\$\phi\$ 5.6 mm) assures high reliability.

Application

- Optical disc memories
- · Optical equipment

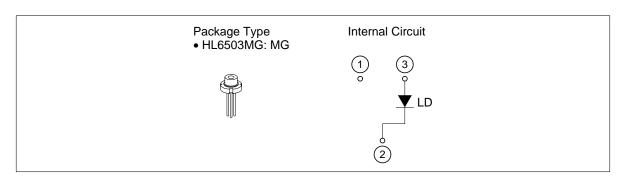
Features

High output power : 50 mW (CW)
Visible light output : λp = 664 nm Typ

• Small package : φ 5.6 mm

• Low astigmatism : $5 \mu m \text{ Typ } (P_0 = 5 \text{ mW})$

Internal Circuit





HL6503MG

Absolute Maximum Ratings $(T_C = 25^{\circ}C)$

Item	Symbol	Value	Unit	
Optical output power	Po	50	mW	
Pulse optical output power	P _{o(pulse)}	70 *	mW	
Laser diode reverse voltage	$V_{R(LD)}$	2	V	
Operating temperature	Topr	-10 to +60	°C	
Storage temperature	Tstg	-40 to +85	°C	

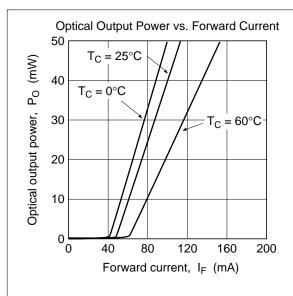
Note: Pulse condition : Pulse width = 100 ns, duty = 50%

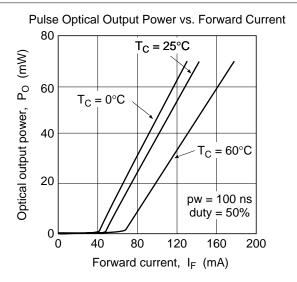
Optical and Electrical Characteristics ($T_C = 25^{\circ}C$)

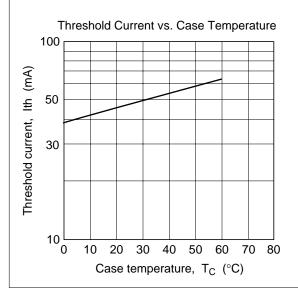
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Optical output power	Po	50	_	_	mW	Kink free *
Pulse optical output power	P _{O(pulse)}	70	_	_	mW	Kink free *
Threshold current	lth	30	45	60	mA	_
Operating current	lop		115	135	mA	P _o = 50 mW
Operating voltage	V _{OP}	2.1	2.6	3.0	V	P _o = 50 mW
Beam divergence parallel to the junction	θ//	7	8.5	11	deg.	P _o = 50 mW
Beam divergence parpendicular to the junction	θΤ	18	21	26	deg.	P _o = 50 mW
Asitgmatism	A _s		5	_	μm	$P_{o} = 5 \text{ mW}, NA = 0.55$
Lasing wavelength	λр	655	664	667	nm	$P_{\circ} = 50 \text{ mW}$

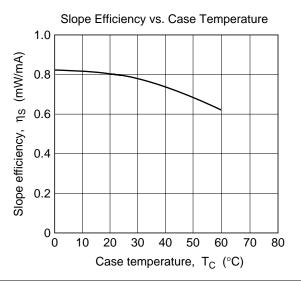
Note: Kink free is confirmed at the temperature of 25°C.

Typical Characteristic Curves



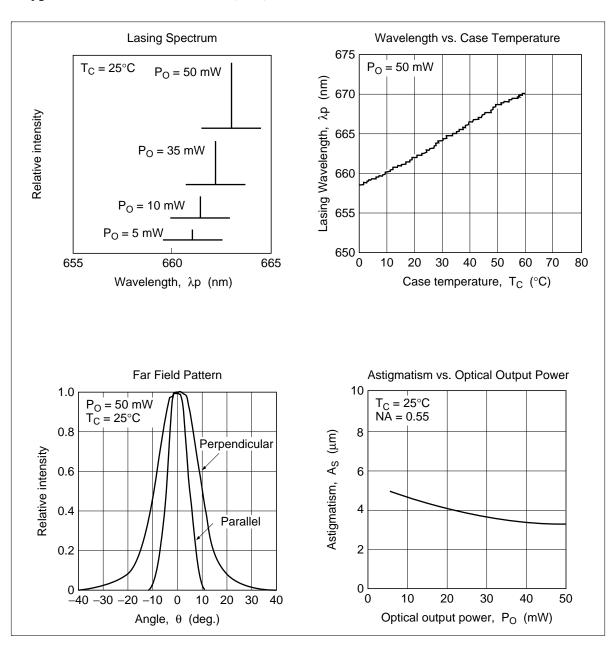




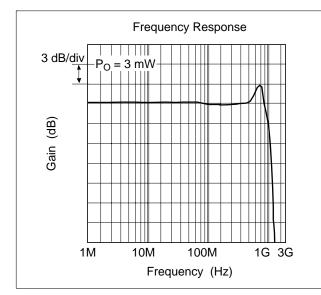


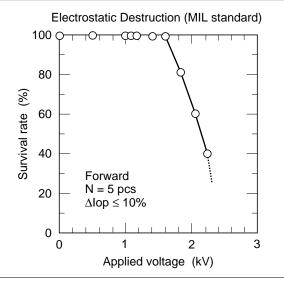
HL6503MG

Typical Characteristic Curves (cont)



Typical Characteristic Curves (cont)

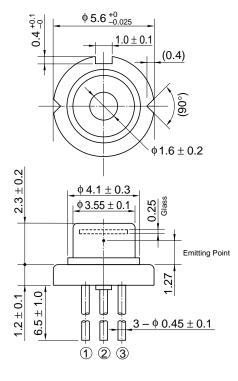


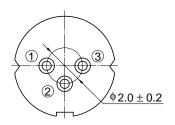


Package Dimensions

Unit: mm







Hitachi Code	LD/MG			
JEDEC	_			
EIAJ	_			
Mass (reference value)	0.3 g			

Cautions

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